

	<h2 style="color: red;">NTD60N02RG</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD60N02RG</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 25V 8.5A DPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD60N02RG.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 9369 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD60N02RG</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 25V 8.5A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	9369 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.25W (Ta), 58W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8.5A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	10.5 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1330pF @ 20V
Verpackung	Tube



















































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Sie können auch interessiert sein:

 <p><b>NTD60N03-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 28V 60A IPAK</p>	 <p><b>NTD60N02RT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 8.5A DPAK</p>	 <p><b>NTD60N02R-032</b> O NTD60N02R-032 O</p>	 <p><b>NTD60N02R-1R</b> ON NTD60N02R-1R ON</p>
 <p><b>NTD60N02RG-1G</b> ON NTD60N02RG-1G ON</p>	 <p><b>NTD60N02RT</b> ON NTD60N02RT ON</p>	 <p><b>NTD60N02R-035</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 8.5A IPAK</p>	 <p><b>NTD60N02R-35G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 8.5A IPAK</p>

### heiße Teile

Mehr

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